

# SSM6N15FE

High Speed Switching Applications  
 Analog Switching Applications

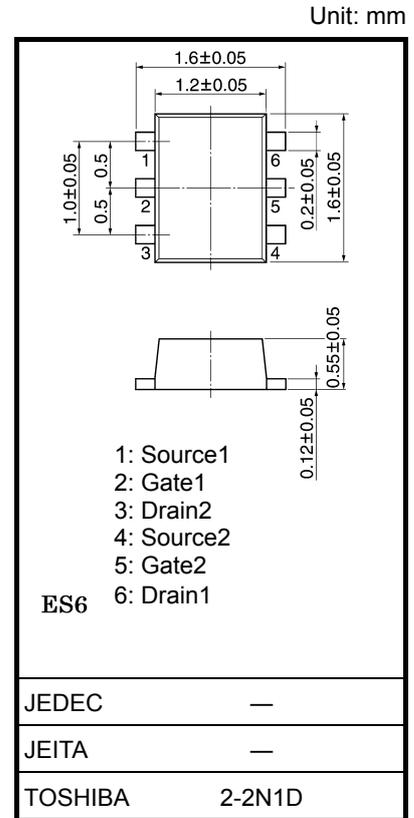
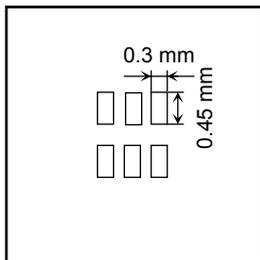
- Small package
- Low ON resistance :  $R_{on} = 4.0 \Omega$  (max) (@ $V_{GS} = 4 V$ )  
 :  $R_{on} = 7.0 \Omega$  (max) (@ $V_{GS} = 2.5 V$ )

## Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

| Characteristics                     |       | Symbol         | Rating  | Unit |
|-------------------------------------|-------|----------------|---------|------|
| Drain-Source voltage                |       | $V_{DS}$       | 30      | V    |
| Gate-Source voltage                 |       | $V_{GSS}$      | ±20     | V    |
| Drain current                       | DC    | $I_D$          | 100     | mA   |
|                                     | Pulse | $I_{DP}$       | 200     |      |
| Drain power dissipation (Ta = 25°C) |       | $P_D$ (Note 1) | 150     | mW   |
| Channel temperature                 |       | $T_{ch}$       | 150     | °C   |
| Storage temperature range           |       | $T_{stg}$      | -55~150 | °C   |

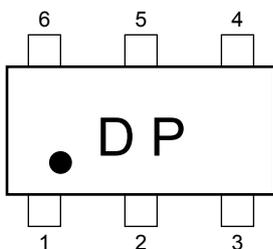
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating, mounted on FR4 board  
 (25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 0.135 mm<sup>2</sup> × 6)

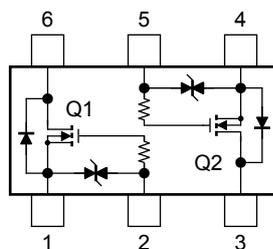


Weight: 3mg (typ.)

### Marking



### Equivalent Circuit (top view)



### Handling Precaution

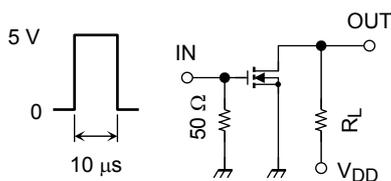
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

| Characteristics                |               | Symbol        | Test Condition   | Min | Typ. | Max     | Unit          |
|--------------------------------|---------------|---------------|--|-----|------|---------|---------------|
| Gate leakage current           |               | $I_{GSS}$     | $V_{GS} = \pm 16\text{ V}, V_{DS} = 0$                                     | —   | —    | $\pm 1$ | $\mu\text{A}$ |
| Drain-Source breakdown voltage |               | $V_{(BR)DSS}$ | $I_D = 0.1\text{ mA}, V_{GS} = 0$  | 30  | —    | —       | V             |
| Drain cut-off current          |               | $I_{DSS}$     | $V_{DS} = 30\text{ V}, V_{GS} = 0$   | —   | —    | 1       | $\mu\text{A}$ |
| Gate threshold voltage         |               | $V_{th}$      | $V_{DS} = 3\text{ V}, I_D = 0.1\text{ mA}$                                 | 0.8 | —    | 1.5     | V             |
| Forward transfer admittance    |               | $ Y_{fs} $    | $V_{DS} = 3\text{ V}, I_D = 10\text{ mA}$                                  | 25  | —    | —       | mS            |
| Drain-Source ON resistance     |               | $R_{DS(ON)}$  | $I_D = 10\text{ mA}, V_{GS} = 4\text{ V}$                                  | —   | 2.2  | 4.0     | $\Omega$      |
|                                |               |               | $I_D = 10\text{ mA}, V_{GS} = 2.5\text{ V}$                                | —   | 4.0  | 7.0     |               |
| Input capacitance              |               | $C_{iss}$     | $V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$                        | —   | 7.8  | —       | pF            |
| Reverse transfer capacitance   |               | $C_{rss}$     |  | —   | 3.6  | —       | pF            |
| Output capacitance             |               | $C_{oss}$     |  | —   | 8.8  | —       | pF            |
| Switching time                 | Turn-on time  | $t_{on}$      | $V_{DD} = 5\text{ V}, I_D = 10\text{ mA},$<br>$V_{GS} = 0 \sim 5\text{ V}$ | —   | 50   | —       | ns            |
|                                | Turn-off time | $t_{off}$     |  | —   | 180  | —       |               |

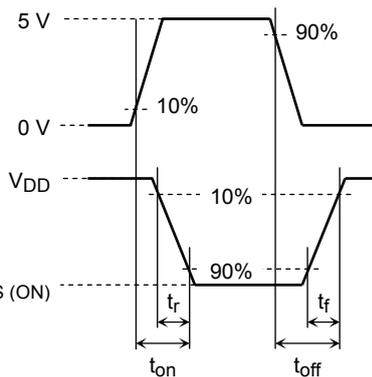
## Switching Time Test Circuit

(a) Test circuit

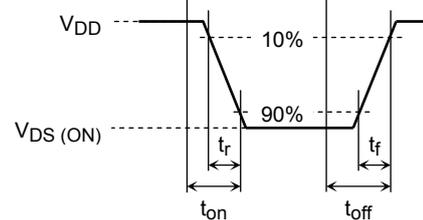


$V_{DD} = 5\text{ V}$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5\text{ ns}$   
 $(Z_{out} = 50\ \Omega)$   
 Common Source  
 $T_a = 25^\circ\text{C}$

(b)  $V_{IN}$



(c)  $V_{OUT}$

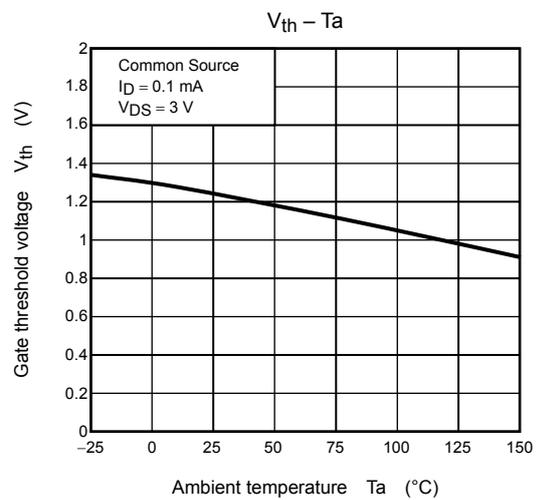
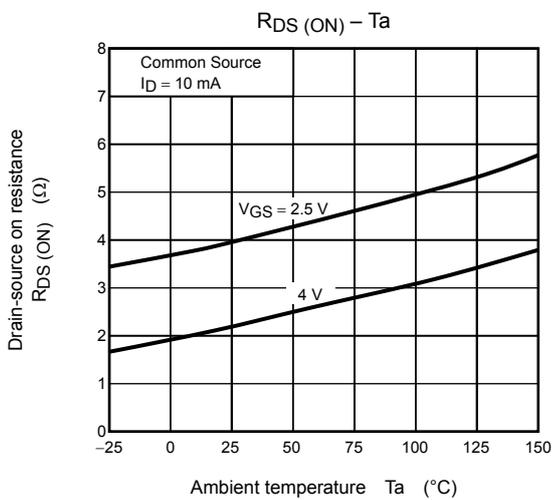
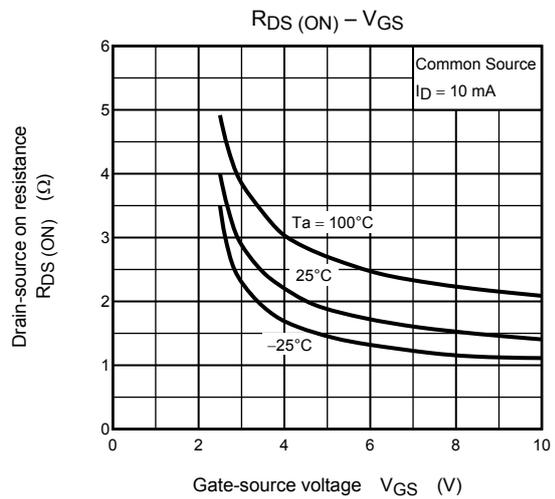
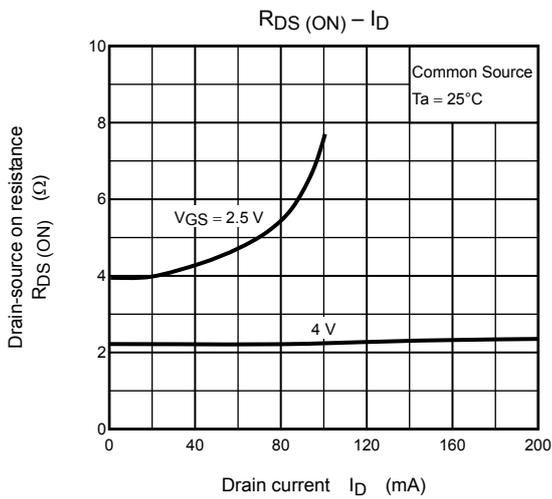
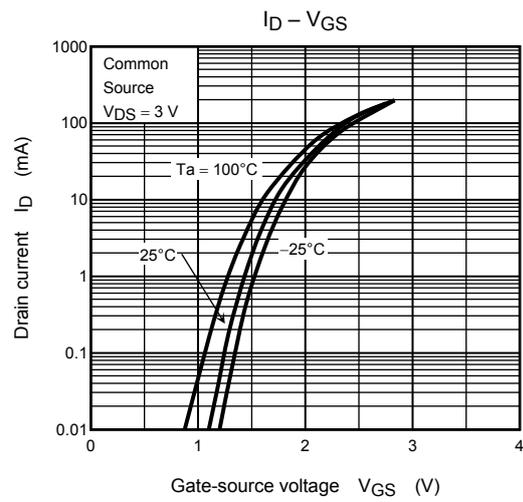
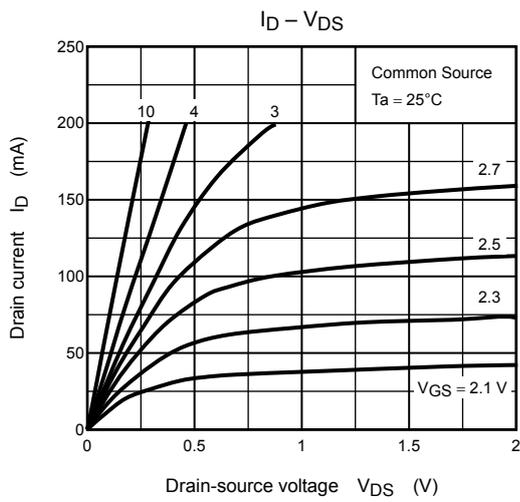


## Precaution

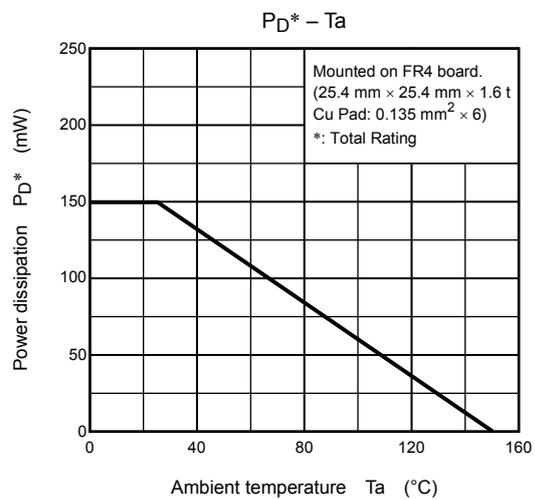
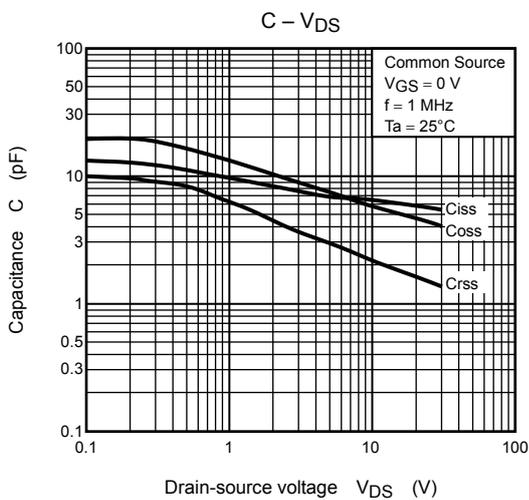
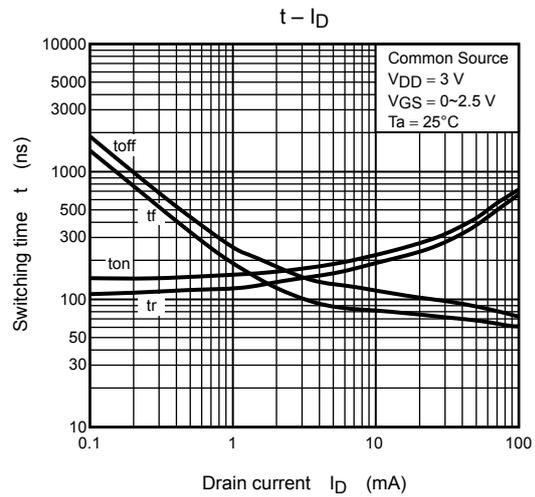
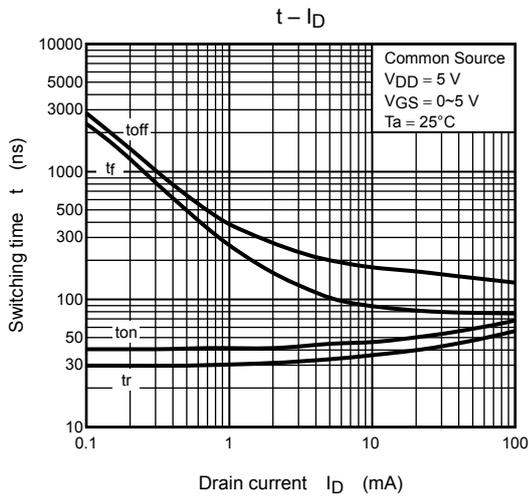
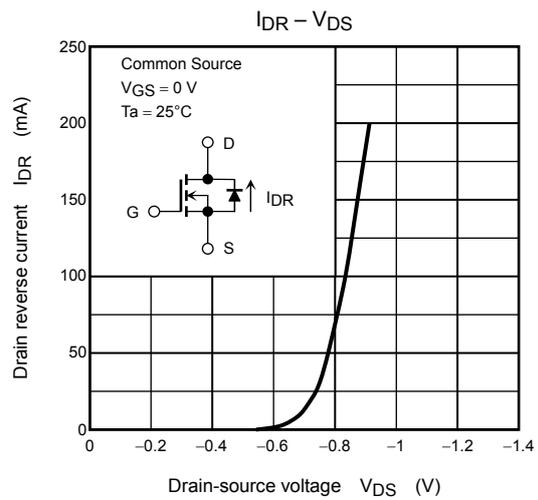
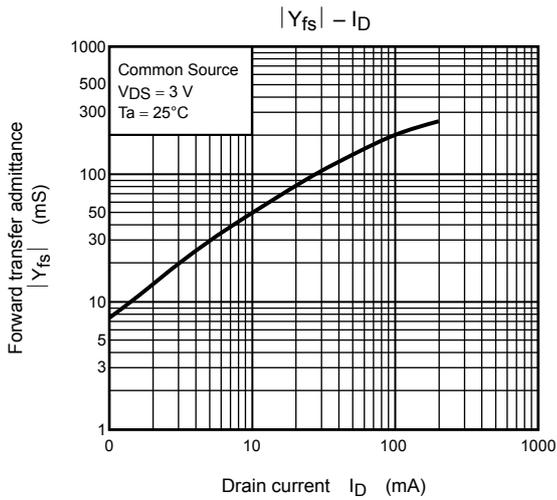
$V_{th}$  can be expressed as voltage between gate and source when low operating current value is  $I_D = 100\ \mu\text{A}$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires lower voltage than  $V_{th}$ . (Relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ )

Please take this into consideration for using the device.

## (Q1, Q2 Common)



## (Q1, Q2 Common)



\*: Total rating

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20070701-EN GENERAL

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